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Supplemental Information

Mafb and *c-Maf* Have Prenatal Compensatory

and Postnatal Antagonistic Roles in Cortical

Interneuron Fate and Function

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MAFB and c-MAF expression in late MGE progenitors E12.5 MGE



Figure S1. (A-F) MAFB and C-MAF expression at E12.5 and E17.5; (G-L): Effect of *Maf* mutations on the expression of *Mafb* and *c-Maf* RNA; (M-AJ'): MAFB and C-MAF expression in dividing MGE cells. *Related to Figure 1 and Table S1*.

(A-F) Immunofluorescent images from E12.5 basal ganglia and E17.5 neocortices showing MAFB and c-MAF positive cells. (G-L) Effect of *Mafb* and *c-Maf* deletion on RNA expression in the *Mafb* cKO/*c-Maf* cKOs at E15.5, compared to control brain. (M-Q) Immunofluorescent images from E12.5 MGE that show co-localization of MAFB and EdU. EdU was injected when embryos were E12.5 and was incubated for an hour to label the majority of VZ progenitors and some SVZ progenitors. (R-W) Immunofluorescent images from E15.5 MGE that show co-localization of MAFB and MCM2, a pan progenitor marker. (X-AB') Immunofluorescent images from E12.5 MGE that show co-localization of c-MAF and EdU. (AC'-AH') Immunofluorescent images from E15.5 MGE that show co-localization of c-MAF and EdU. (AC'-AH') Immunofluorescent images from E15.5 MGE that show co-localization of c-MAF and EdU. (AC'-AH') Immunofluorescent images from E15.5 MGE that show co-localization of c-MAF and EdU. (AC'-AH') Immunofluorescent images from E15.5 MGE that show co-localization of c-MAF and EdU. (AC'-AH') Immunofluorescent images from E15.5 MGE that show co-localization of c-MAF and EdU. (AC'-AH') Immunofluorescent images from E15.5 MGE that show co-localization of c-MAF and EdU. (AC'-AH') Immunofluorescent images from E15.5 MGE that show co-localization of c-MAF and EdU. (AC'-AH') Immunofluorescent images from E15.5 MGE that show co-localization of c-MAF and EdU. (AC'-AH') Immunofluorescent images from E15.5 MGE that show co-localization of c-MAF and EdU. (AC'-AH') Immunofluorescent images from E15.5 MGE that show co-localization of c-MAF and EdU. (AC'-AH') Immunofluorescent images from E15.5 MGE that show co-localization of c-MAF and EdU at E12.5. Data are shown as mean \pm SEM. Six technological replicates were used for analysis. Scale bar in (B) and (G) = 250um. Scale bar in (C) = 100um. Scale bar in (M, R, X and AC') = 100um. Scale bar in (N, T and Y) = 50 um. Scale bar in (AE') = 25um.



Figure S2. Mafb/ c-Maf cKO and cDKOs have gradual reduction of CINs by P35. Related to Figure 2 and Table S2.

(A-T) Immunofluorescent images from E13.5/ E15.5/ P0 neocortices and P7/ P16 somatosensory cortices show native tdTomato⁺ CIN distribution. (U) Quantification of the proportion of tdTomato⁺ cells by regions at E15.5 neocortex. Zone 1= marginal zone; Zone 2 = cortical plate and subplate; Zone 3 = intermediate zone; Zone 4 = deep migration/subventricular zone; Zone 5= ventricular zone. (V) Quantification of the proportion of tdTomato⁺ cells by regions at P0 neocortex. Cortex was binned into 5 zones roughly by equal distance, but zone 1 was focused on the marginal zone. (W) Quantification of the number of tdTomato⁺ cells per mm² in the neocortices or somatosensory cortices. Data are expressed as the mean \pm SEM. *p < 0.05, **p < 0.01, ***p < 0.001. (n) = 3-4 for all groups. Scale bar in (D, H, L, P and T) = 100 µm. The P35 data is the same as shown in Fig. 2.



Figure S3. (A-E): Effect of *Maf* single and double conditional mutants (*Nkx2.1-Cre*) on the expression of *Sst* RNA at E15.5; (F-J): Effect of *Maf* single and double conditional mutants (*Nkx2.1-Cre*) on the numbers of hippocampal tdTomato⁺ interneurons at P0; (K-O) 799-CreER activity initiates in the late SVZ (SVZ2) of MGE; (P-Y) Fate mapping of *Sst-IRES-Cre* lineage CINs in the adult CINs. *Related to Figure 2 and Figure 4.*

Top: The schema shows the cell types in which each Cre line initiates recombination.

Nkx2.1-Cre data: (A-D) *Sst in situ* hybridization at E15.5 in control, *Mafb* cKO, *c-Maf* cKO and cDKO. (E) Quantification of *Sst*⁺ CINs per mm² by region in the neocortex in 4 different *Maf* genotypes. (n)=3-4 for all groups. Note that in the *c-Maf* cKOs, there was no reduction in the *Sst*⁺ CIN density count. (F-I) Immunofluorescent images of the P0 hippocampus of the 4 different *Maf* genotypes. Boxed region in (F) highlights the CA1 region used for tdTomato⁺ CIN quantification for each genotype. (J) Quantification of tdTomato⁺ CINs per mm² in the CA1 region; (n)=4 for all *Maf* genotypes.

799-CreER data: (K) Immunofluorescent images from E12.5 MGE that show co-staining of tdTomato (799-CreER lineage), EdU and KI67. (L) Higher magnification views (imaged from the boxed region in K) showing colocalization of tdTomato and KI67 in the SVZ2 of the MGE. (M-O) Immunofluorescent images from E12.5 embryonic basal ganglia that show co-staining of tdTomato, EdU and MAFB. Note the boxed region in (L) that show colocalization of tdTomato and MAFB, providing evidence that 799-CreER activity and MAFB expression both initiate in SVZ2 (late SVZ) of the MGE.

Sst-IRES-Cre data: (P-S) Immunofluorescent images from P35 neocortex that show the overlay of SST⁺ CINs with the *Sst-IRES-Cre* lineage (tdTomato⁺) and Lhx6-GFP⁺ cells (mostly MGE-derived CINs). (T-W) Immunofluorescent images from P35 neocortex that show the overlay of PV⁺ CINs with the *Sst-IRES-Cre* lineage (tdTomato⁺) and Lhx6-GFP⁺ cells. (X) Quantification of the percentage of tdTomato⁺ CINs, Lhx6-GFP⁺ CINs or tdTomato⁻;GFP⁺ CINs that express SST. 80% of tdTomato⁺ cells (*Sst-IRES-Cre*-lineage) were SST⁺. ~35% of Lhx6-GFP⁺ CINs were SST⁺. None of the tdTomato⁻/GFP⁺ cells were SST⁺. (Y) Quantification of the percentage of tdTomato⁺ CINs, Lhx6-GFP⁺ CINs or tdTomato⁻;GFP⁺ CINs that express PV. ~8% of tdTomato⁺ cells (*Sst-IRES-Cre*-lineage) were PV⁺. ~55% of *Lhx*6-GFP⁺ CINs were PV⁺. ~85% of the tdTomato⁻/GFP⁺ cells were PV⁺. Together, this data provide evidence that most of the CINs derived from the *Sst-IRES-Cre* lineage are SST⁺. Data are expressed as the mean ± SEM. *p < 0.05, **p < 0.01, ****p < 0.0001. Scale bars in (**I, K and W**) =100um; Scale bar in (**L**) = 50 µm; Scale bar in (**D and O**) = 200 um; Abbreviations: VZ: ventricular zone, SVZ1: early subventricular zone, SVZ2: late subventricular zone, MZ: marginal zone.



Figure S4. MGE progenitors show no differences in proliferation indices in *Maf* **cDKOs.** *Related to Figure 2, Figure 3, Figure 4 and Figure 5.*

(A) Schema depicting the EdU 30-minute pulse assay. Briefly, EdU was injected into pregnant females when embryos were E13.5 and assessed after 30 minutes. Immunofluorescent images show the MGE co-stained with EdU and DAPI (**B**-C). (**D**) Quantification of EdU⁺ progenitors per mm² by region. Immunofluorescent images from either E13.5 (**E and F**) or E15.5 (**G and H**) MGEs that were co-labeled for tdTomato and PH3. Quantification of the numbers of PH3⁺ cells/area were calculated at E13.5 (**I**) and E15.5 (**J**) for both VZ and SVZ regions. Data are expressed as the mean \pm SEM. (n)=3-4 for all groups. Student t-test was done but found no significant changes. Scale bars in (**C and H**) = 100 µm. Abbreviations: VZ: ventricular zone, SVZ: subventricular zone



Figure S5. *In situ* hybridization for genes that regulate MGE and CIN development. *Related to Figure 2, Figure 3, Figure 4, and Figure 5.*

Rostral and caudal coronal hemisections through the telencephalon; *in situ* hybridization shows RNA expression of *Nkx2.1* (**A**, **A'**, **B** and **B'**), *Lhx*6 (**C**, **C'**, **D** and **D'**), *Delta1* (**E**, **E'**, **F** and **F'**) and *Hes5* (**G**, **G'**, **H** and **H'**) at E13.5. *In situ* hybridizations showing expression of *CoupTFII* (**I**, **I'**, **J** and **J'**), *Sox*6 (**K**, **K'**, **L** and **L'**), *CyclinD2* (**M**, **M'**, **N** and **N'**), *Cxcr7* (**O**, **O'**, **P** and **P'**) and *Sp9* (**Q**, **Q'**, **R** and **R'**) at E14.5. In all panels, control hemispheres are on the left and cDKO hemispheres are on the right. Scale bars in (**H'**, **P'** and **R'**) = 250 μm.



Figure S6. (A-C) Synaptic excitation and intrinsic excitability of RS CINs in control, *Mafb* cKO, *c-Maf* cKO and cDKO mice. (D-H) Neurite complexity analysis on CINs from control, *Mafb* cKO, *c-Maf* cKO and cDKO following 14 days of *in vitro* cortical culture. *Relate to Figure 6.*

(A) Quantification (mean \pm SEM) of the amplitude, frequency and decay time constant of sEPSCs (Vhold = -70mV) in RS CINs. Note no change in amplitude or decay of sEPSCs and the increased frequency in *Mafb* and *c-Maf* cKOs compared with controls. *p < 0.05, One Way ANOVA Kruskal-Wallis. (Control: 7 cells; *Mafb* cKO:11 cells; *c-Maf* cKO: 6 cells; cDKO: 4 cells). (B) F-I curve: Plot of the mean action potential firing frequency as a function of current intensity injected in the RS cells. Overall, no significant change was observed between groups. (C) Representative traces from RS CINs for each genotype. (D) Schema depicting the regions that were quantified: soma size "1", dendrite thickness "2", primary neurite "3" and secondary neurite "4". (E) Quantification (mean \pm SEM) of soma size for 4 *Maf* genotypes. (Control: 15 cells; *Mafb* cKO: 12 cells; *c-Maf* cKO: 19 cells; cDKO: 15 cells) (F) Quantification (mean \pm SEM) of proximal dendrite thickness. (Control: 43 neurites; *Mafb* cKO: 35 neurites; *c-Maf* cKO: 59 neurites; DKO: 38 neurites) (G) Quantification (mean \pm SEM) of primary neurite numbers. (Control: 14 cells; *Mafb* cKO: 12 cells; *c-Maf* cKO: 17 cells; *c-Maf* cKO: 20 cells; *c-Maf* cKO: 17 cells; *c-Maf* cKO: 21 cells; *c-Maf* cKO: 24 cells). **p < 0.001; One Way ANOVA followed by Turkey's multiple comparisons test.



Figure S7. Models of *Mafb/c-Maf* **function in MGE CIN cell type specification and dendritic/synaptic/function maturation.** *Related to Figure 2, Figure 3, Figure 4, Figure 5, Figure 6 and Figure 7.*

Upper panel: Hypothesis for redundant prenatal roles for *Mafb* and *c-Maf* in CIN cell type specification. In the absence of both *Mafb* and *c-Maf* (cDKO) in the SVZ, there is excessive generation of SST⁺ CINs. In the postnatal brain, after normalizing for the loss of CINs, there are decreased numbers of PV⁺ CINs. We hypothesize that the reduction of PV⁺ CINs may due in part to a role of *Mafb* and *c-Maf* in promoting PV⁺ CIN identity in the SVZ of the MGE. Furthermore, we postulate that *Mafb* and *c-Maf* repress SST⁺ CIN production/identity in the SVZ.

Lower panel: Opposing postnatal roles for *Mafb* and *c-Maf* in cortical excitability. In the *Mafb* and *c-Maf* cKO cortices, the numbers of MGE-derived CINs are roughly equal. However, loss of *Mafb* results in CINs that have (1) less post-synaptic densities (*= showing a decrease trend but didn't reach statistical significance), (2) receive less EPSCs and (3) a cortex that is hyper-responsive to a stimulus, while loss of *c-Maf* results in CINs that have (1) higher neurite complexity, (2) more post-synaptic densities, (3) receive greater EPSCs and (4) a cortex that is hypo-responsive to a stimulus. Notably, cDKO CINs have normal numbers of post-synaptic densities, receive a normal number of EPSCs and have a cortex that responded to a stimulus in a manner in between that of *Mafb* and *c-Maf* single cKOs.

	P35	Control	<i>Mafb</i> cKO	<i>c-Maf</i> cKO	<i>Maf</i> cDKO
	Tissue		Total Nkx2.1-Cre-line	eage cells/mm ² ± SEM	
	Hippocampus	266.1 ± 13.8	250.5 ± 5.2	257.5 ± 14.3	** 195.9 ± 8.2
	Neocortex	260.8 ± 10.1	** 194.5 ± 12.8	*** 176.7 ± 6.9	**** 87.2 ± 6.4
	Striatum	333.7 ± 9.8	* 298.4 ± 3.3	307.1 ± 6.3	*** 269.7 ± 7.0
Marker	Tissue	То	tal Nkx2.1-Cre-lineage	*/marker* cells/mm ² ± \$	SEM
	Hippocampus	73.7 ± 3.1	68.1 ± 3.5	73.1 ± 8.3	*** 26.0 ± 3.4
PV			* 76.3 ± 3.7	* 77.1 ± 6.3	*** 24.6 ± 6.5
	Neocortex	113.0 ± 9.5	(32.5% decrease)	(32% decrease)	(78.2% decrease)
	Striatum	73.4 ± 4.7	*** 38.1 ± 3.9	*** 44.0 ± 4.8	**** 7.6 ± 2.2
	Hippocampus	46.9 ± 9.5	50.7 ± 4.7	49.4 ± 9.9	26.1 ± 3.4
SST			89.1 ± 7.4	* 72.0 ± 5.0	*** 31.0 ± 3.4
	Neocortex	101.5 ± 8.8	(12% decrease)	(29% decrease)	(69% decrease)
	Striatum	35.9 ± 2.5	32.4 ± 2.2	34.8 ± 2.2	34.2 ± 2.2
Marker	Tissue	% NI	kx2.1-Cre-lineage cells	that express marker :	± SEM
D\/	Hippocampus	28.4 ± 1.6	28.7 ± 0.7	29.5 ± 2.3	*** 14.5 ± 1.4
FV	Neocortex	41.2 ± 1.7	39.7 ± 1.8	44.5 ± 0.8	*** 25.2 ± 3.4
	Striatum	22.7 ± 1.8	*** 12.6 ± 1.3	** 14.0 ± 1.3	*** 2.8 ± 0.8
еет	Hippocampus	17.9 ± 0.6	23.3 ± 2.3	21.8 ± 4.2	14.2 ± 2.2
331	Neocortex	36.2 ± 1.8	41.1 ± 1.9	37.5 ± 0.5	38.1 ± 4.2
	Striatum	10.7 ± 0.9	11.1 ± 0.8	11.5 ± 0.7	12.6 ± 0.3

Table S2.	Cumulative cell	counts of Nkx2.	1-Cre-lineage	cells in the	neocortex and	hippocamp	ans
Table 52.	Cumulative cen	counts of maz.	1-Crt-inicage	cens in the	neocor ica anu	mppocamp	us

	Control	Mafb cKO	<i>с-Ма</i> f сКО	Maf cDKO		
Tissue	Total <i>Nkx2.1-Cre-</i> lineage cells/mm ² ± SEM					
P7 Hippocampus	369.95 ± 8.16	* 258.88 ± 17.03	349.55 ± 20.1	398.86 ± 26.46		
P16 Hippocampus	266.06 ± 13.76	250.48 ± 5.21	257.54 ± 14.31	* 195.86 ± 8.24		

p value * < 0.05, ** < 0.01, *** < 0.001, **** < 0.0001 compared to control group

Table S2. Cumulative cell counts of *Nkx2.1-Cre*-lineage cells in the neocortex and hippocampus. *Related to Figure 2, Figure 4 and Figure S3*

(**Top**) Quantification of the numbers of *Nkx2.1-Cre*⁺ cells from all genotypes at P35. (**Bottom**) Quantification of the numbers of *Nkx2.1-Cre*⁺ cells from all genotypes in the hippocampus at P7 and P16. Panels at the top show both proportion and cell density of tdTomato⁺ cells that express SST or PV in the somatosensory cortex and hippocampus. Panels at the bottom show the tdTomato⁺ cell density count in the whole hippocampus (including DG, CA1 and CA2/3). Data are expressed as the mean \pm SEM. *p < 0.05, **p <0.01, ***p < 0.001, ***p < 0.001.

	Passive electric membrane properties									
Cell	Genotype	Vm (mV)	Rin (MΩ)	τm (ms)	Cm (pF)	# of				
Туре						cells				
FS	Control	-69.4 ± 1.7 (27)	268.7 ± 33.7 (18)	18.1±1.8 (17)	45.3 ± 4.5 (18)	27				
	Mafb cKO	-67.6 ± 1.5 (26)	278.7 ± 25.8 (25)	21.4 ± 1.6 (24)	41.5 ± 2.9 (18)	26				
	<i>c-Maf</i> cKO	-70.2 ± 1.1 (41)	252.3 ± 22.2 (38)	19.8 ± 1.1 (37)	36.9 ± 3.6 (37)	41				
	cDKO	-71.3 ± 1.8 (8)	225.5 ± 50.4 (9)	19.9 ± 2.4 (9)	33.0 ± 6.3 (10)	8				
	Statistics	ns	ns	ns	ns					
RS	Control	-70.1 ± 1.3 (16)	528.6 ± 34.9 (7)	34.0± 4.3 (7)	45.1 ± 3.8 (7)	16				
	Mafb cKO	-62.4 ± 2.8 (11)	320.2 ± 43.3c(11)	23.2 ± 2.6 (11)	48.1 ± 4.8 (11)	11				
	<i>c-Maf</i> cKO	-72.0 ± 1.5 (19)	570.5 ± 108.9 (8)	37.0 ± 8.0 (8)	32.0 ± 4.1 (11)	19				
	cDKO	-72.0 ± 3.4 (6)	238.7 ± 46.8 (5)	24.6 ± 4.0 (5)	58.1 ± 9.3 (7)	6				
	Statistics	p=0.01 (Control vs <i>Mafb</i> cKO) p= 0.003 (<i>Mafb</i> cKO vs <i>c-Maf</i> cKO)	p=0.004 (Control vs <i>Mafb</i> cKO) p=0.0005 (Control vs cDKO) p=0.03 (<i>Mafb</i> cKO vs <i>c-Maf</i> cKO) p=0.04 (<i>c-Maf</i> cKO vs cDKO)	p=0.036 (Control vs <i>Mafb</i> cKO)	p=0.04 (Control vs <i>c-Maf</i> cKO) p=0.018 (<i>Mafb</i> cKO vs <i>c-Maf</i> cKO) p=0.01 (<i>c-Maf</i> cKO vs cDKO)					

Table S3. Passive and Active electric membrane properties of layer V CINs

	Active electric membrane properties									
Cell	Genotype	AP threshold (mV)	AP amplitude (mV)	AP Full-duration (ms)	AP Half-duration (ms)	# of				
Туре						cells				
FS	Control	-55.8 ± 0.9	58.5 ± 2.3	1.4 ± 0.1	0.7 ± 0.05	19				
	Mafb cKO	-57.9 ± 0.8	65.8 ± 2.3	1.6 ± 0.1	0.7 ± 0.03	24				
	<i>c-Maf</i> cKO	-54.2 ± 0.7	60.1 ± 1.3	1.4 ± 0.1	0.6 ± 0.03	38				
	cDKO	-54.97 ± 1.1	60.8 ± 2.0	1.5 ± 0.1	0.6 ± 0.04	9				
	Statistics	p=0.001 (<i>Mafb</i> cKO vs <i>c-Maf</i> cKO) p=0.049 (<i>Mafb</i> cKO vs cDKO)	p=0.03 (Control vs <i>Mafb</i> cKO) p=0.025 (<i>Mafb</i> cKO vs <i>c-Maf</i> cKO)	p=0.04 (<i>Mafb</i> cKO vs <i>c-Maf</i> cKO)	p=0.02 (<i>Mafb</i> cKO vs <i>c-Maf</i> cKO) p=0.047 (<i>Mafb</i> cKO vs cDKO)					
RS	Control	-58.2 ± 0.8	59.7 ± 5.2	2.4 ± 0.3	1.1 ± 0.09	5				
	Mafb cKO	-54.9 ± 1.2	56.1 ± 4.4	2.2 ± 0.3	0.9 ± 0.09	8				
	<i>c-Maf</i> cKO	-53.9 ± 1.2	49.4 ± 2.7	2.3 ± 0.3	0.9 ± 0.1	8				
	cDKO	55.7 ± 4.5	45.7 ± 7.3	2.1 ± 0.1	0.8 ± 0.04	3				
	Statistics	p=0.02 (Control vs <i>c-Maf</i> cKO)	ns	ns	ns					

Table S3. Passive and active electric membrane properties of CINs. Related to Figure 6 and Figure S6.

Quantification of the numbers of passive (**Top**) and active (**Bottom**) electric membrane properties of fast-spiking (FS) and regularspiking (RS) CINs in Control, *Mafb* cKO, *c-Maf* cKO and cDKO. Data are expressed as the mean \pm SEM.

Table S4. Properties of spontaneous excitatory post-synaptic currents (sEPSCs) of layer V CINs for all groups and mEPSCs of layer V CINs for Control and *Mafb* cKO

	sEPSCs								
Cell Type	Genotype	Amplitude (pA)	Decay τ (ms)	Frequency (Hz)	# of cells				
FS	Control	23.9 ± 1.9	1.2 ± 0.2	8.4 ± 1.8	13				
	Mafb cKO	17.4 ± 0.6	1.2 ± 0.1	6.8 ± 1.5	24				
	<i>c-Maf</i> cKO	20.9 ± 0.8	1.0 ± 0.1	16.6 ± 3.2	33				
	cDKO	23.2 ± 2.5	1.4 ± 0.2	9.4 ± 3.4	7				
	Statistics	p=0.0004 (Control vs <i>Mafb</i> cKO) p=0.002 (<i>Mafb</i> cKO vs <i>c-Maf</i> cKO) p=0.002 (<i>Mafb</i> cKO vs cDKO)	p=0.03 (c- <i>Maf</i> cKO vs cDKO)	р=0.015 (<i>Mafb</i> сКО vs <i>с-Maf</i> сКО)					
RS	Control	17.4 ± 1.2	2.0 ± 0.4	1.2 ± 0.7	7				
	Mafb cKO	18.1 ± 1.1	1.7 ± 0.3	8.6 ± 2.4	11				
	<i>c-Maf</i> cKO	17.7 ± 1.3	1.4 ± 0.3	12.2 ± 4.8	6				
	cDKO	16.7 ± 1.2	2.7 ± 0.7	0.8 ± 0.2	4				
	Statistics	ns (p>0.1)	ns (p>0.1)	p=0.029 (Control vs <i>Mafb</i> cKO) p=0.03 (Control vs <i>c-Maf</i> cKO)					

mEPSCs							
Measurement	Unit	Control	Mafb cKO	Statistics			
Frequency	Hz	3.785 ± 0.7408	8.789 ± 2.748	Ns			
Amplitude	pА	18.32 ± 0.963	12.54 ± 0.4074	P<0.0001			
Charge	fC	32.56 ± 3.667	23.29 ± 3.299	P<0.01			
Tau Decay	ms	1.588 ± 0.1679	1.973 ± 0.2371	ns			
Rise Time	ms	0.2996 ± 0.009	0.326 ± 0.01389	ns			
Half-width		1.996 ± 0.2647	2.252 ± 0.3733	ns			
Number of cells		24	19				
Number of mice		2	2				

Table S4. Properties of spontaneous excitatory post-synaptic currents (sEPSCs) of layer V CINs for all groups and mEPSCs of layer V CINs for Control and *Mafb* cKO. *Related to Figure 6 and Figure 56*.

(**Top**) Quantification of the numbers of properties of spontaneous excitatory post-synaptic currents (sEPSCs) of fast-spiking (FS) and regular-spiking (RS) CINs in Control, *Mafb* cKO, *c-Maf* cKO and cDKO. One Way ANOVA Kruskal-Wallis followed by Dunn's multiple comparisons test was used for the analysis. (**Bottom**) Quantification of the numbers of properties of mEPSCs of layer V CINs for Control and *Mafb* cKO. Mann-Whitney test was used for the analysis. Data are expressed as the mean \pm SEM. *p < 0.05, **p <0.01, ***p < 0.001, ***p < 0.001.

		From Figure 8D						
	Lin	e length p val	ues	Amplitude p values				
Genotypes	Layer ii-iii	Layer iv	Layer v-vi	Layer ii-iii	Layer iv	Layer v-vi		
Control vs. Mafb cKO	< 0.0001	< 0.0001	< 0.0001	< 0.0001	< 0.0001	< 0.0001		
Control vs. c-Maf cKO	0.006	0.02	< 0.0001	< 0.0001	< 0.0001	< 0.0001		
Control vs. cDKO	0.0006	0.03	< 0.0001	< 0.0001	< 0.0001	< 0.0001		
Mafb cKO vs. cDKO	< 0.0001	< 0.0001	< 0.0001	< 0.0001	< 0.0001	< 0.0001		
Mafb cKO vs. c-Maf cKO	< 0.0001	< 0.0001	< 0.0001	< 0.0001	< 0.0001	< 0.0001		
<i>c-Maf</i> cKO vs. cDKO	n.s.	0.0006	< 0.0001	< 0.0001	< 0.0001	< 0.0001		

Table S5. Statistical analysis for local field potential measurement by layers

		From Figure 8E						
	Lin	Line length p values			Amplitude p values			
Genotypes	Layer ii-iii	Layer iv	Layer v-vi	Layer ii-iii	Layer iv	Layer v-vi		
Control vs. Mafb cKO	< 0.0001	< 0.0001	< 0.0001	< 0.0001	< 0.0001	< 0.0001		
Control vs. <i>c-Maf</i> cKO	n.s.	n.s.	0.02	n.s.	n.s.	n.s.		
Control vs. cDKO	n.s.	n.s.	n.s.	n.s.	n.s.	n.s.		
Mafb cKO vs. cDKO	< 0.0001	< 0.0001	n.s.	< 0.0001	0.001	< 0.0001		
Mafb cKO vs. c-Maf cKO	< 0.0001	< 0.0001	0.03	< 0.0001	< 0.0001	0.01		
<i>c-Maf</i> cKO vs. cDKO	n.s.	n.s.	n.s.	n.s.	n.s.	n.s.		

Table S5. Statistical analysis for local field potential measurement by layers. Related to Figure 7.

Statistical analysis results for the local field potential/ current source density measurement by layers. Data presented here are p-values.